The Magnetic Microstructure of Nanostructered Materials

#### Magnetic Microstructure: Magnetic Domains



### Quality factor Q

Character of magnetic domains is determined by quality factor Q (= material parameter)





#### Domain wall

#### Bloch wall width: ~ \sqrt{A/K}

A: exchange constant K: anisotropy constant

#### Single domain particle



Multi-domain sample





Multi-domain particle Single-domain particle

#### Coercivity and grain size



G. Herzer, Nanocrystalline soft magnetic alloys. In: Buschow KHJ, editor. Handbook of Magnetic Materials, vol. 10. Elsevier Science B.V., p.415 (1997)

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- 1. Domains in coarse-grained material
- 2. Domains in amorphous material
- Domains in nanocrystalline, soft magnetic (Q<<1) materials</li>
- 4. Domains in fine- and nanostructured, permanent magnetic (Q>1) materials

#### Overview

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4. Domains in fine- and nanostructured, permanent magnetic (Q>1) materials

#### Non-oriented electrical steel





# Domain character is determined by surface orientation of individual grains

(100) -

related



#### Non-oriented electrical steel



(100)related

(110)-related

basic domain.

Ν

0.5 mm

#### Non-oriented electrical steel





Weak misorientation: Refinement of surface domain width by supplementary domains

(100)-

related



#### Non-oriented electrical steel



#### Non-oriented electrical steel



10 **µ**m

# Increasing misorientation: Domain complexity increases





#### Extreme misorientation: FeSi (111) surface





# Strong misorientation: branched domains -Fine at surface, wide in volume

100 µm (100)-sectional view

#### Extreme misorientation: 2-dim. model









#### Extreme misorientation: 2-dim. model























With decreasing grain size the domains get finer.

With decreasing grain size the domains get finer.

# How is coercivity related to grain size?

# Grain boundary domains

#### Goss sheets



# Grain boundary domains

#### Goss sheets

# Grain boundary domains: avoid (reduce) magnetic charges

interface charge =  $\cos \vartheta_1 - \cos \vartheta_2$ 

#### Grain boundary domains

FeSi non-oriented sheet







 $0.26\ M_s$ 





Coarse-grained

materials









#### Grain boundary domains

Coarse-grained

materials

FeSi non-oriented sheet





# Grain boundary domains

FeSi non-oriented sheet


#### Coarse-grained materials

# Grain boundary domains

FeSi non-oriented sheet



Grain boundary domains: Their reorganization in magnetic field costs energy They are responsible for coercivity.

# Grain boundary domains

Coarse-grained

materials

Their relative volume increases with decreasing grain size Coercivity increases with decreasing grain size



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# Amorphous materials Rapidly quenched amorphous ribbons



- thickness 20 µm
- ferromagnetic
  (with Fe, Ni, Co)
- T<sub>75-83</sub> M<sub>25-17</sub>

T = Fe, Co, NiM = P, C, B, Si, Al...

 no magnetocrystalline anisotropy



#### Magnetic microstructure of amorphous ribbons

# m(r) continuously flowing ? or regular domains ?



#### Excursion:

Some general considerations on anisotropy and domains

# Van den Berg Concept

[H.A.M. van den Berg, 1986]

• Assumption: anisotropy-free film element



expect: continuously flowing m(r)

# Van den Berg Concept

[H.A.M. van den Berg, 1986]

- Assumption: anisotropy-free film element
- Stray-field freedom requires:
  - div m = 0
  - m(x,y) || sample edge
  - m(x,y) || film plane
  - |m| = 1

Conditions cannot be met by continuous pattern (exception: circular element)

Consequence:

Regular domain pattern with discontinuities (domain walls), enforced by element shape to avoid magnetic poles



expect: continuously flowing m(r)









- Take circles that touch edge at two or more points. Centers of circles form walls
- In every circle the magnetization direction must be perpendicular to each touching radius
- If a circle touches edge in more than 2 points: its center forms wall junction
- If touching points fall together: wall ends at center of circle = zone of concentric rotation
- Acute corner: boundary runs into corner



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van den Berg discontinuities are in reality domain walls



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Asymmetric Bloch wall

film thickness > 100 nm

scales with thickness





Permalloy (NiFe)



Asymmetric Bloch wall

film thickness > 100 nm

scales with thickness





Permalloy (NiFe)



Asymmetric Bloch wall

film thickness > 100 nm

scales with thickness





Permalloy (NiFe)



Anisotropy-free film element: Existence of real domain walls does not change van den Berg theory

8

(NiFe)

400 nm thick -----

As

Blo

filr

SCa

thi

>

Transition to three-dimensional bodies (i.e. bulk materials): Replace touching circles by touching spheres Centers of spheres define position of domain walls Expect regular domains with defined walls also in anisotropy-free bulk materials

#### Thickness > 5 $\int A/K_d$ : vortex restricted to surface, Bloch-character in volume





Fe (100) wall, thickness 200 nm

A. Aharoni, J. P. Jakubovocs Phys. Rev. B 43 (1991) 1290



Wall width at surface increases steadily with thickness

Wall width in volume approaches classical value

W. Rave and A. Hubert JMMM 184 (1998) 179

Thickness > 5  $\int A/K_d$  : vortex restricted to surface, Bloch-character in volume

# Bulk low-anisotropy materials: Domain walls required (van den Berg), Wall width scales with √A/K



Wall width at surface increases steadily with thickness

Wall width in volume approaches classical value

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Thickness > 5  $\int A/K_d$  : vortex restricted to surface, Bloch-character in volume

Bulk low-anisotropy materials: Domain walls required (van den Berg), Wall width scales with √A/K

Bulk anisotropy-free materials: Domain walls are not defined anymore Consequence

In bulk materials with vanishing anisotropy we do no expect regular, homogeneously magnetized domains with well defined walls, but continuous patterns

#### Magnetic microstructure of amorphous ribbons





#### Magnetic microstructure of amorphous ribbons



# In amorphous material: Continuously flowing magnetization expected rather than regular domains

#### Amorphous ribbon (as-quenched): hysteresis loop



#### Amorphous ribbon (as-quenched): hysteresis loop







Amorphous ribbons show regular domains and walls (rather than "flowing" patterns)



#### Walls in high-permeable Permalloy cores



Also Permalloy shows (more or less) regular domains walls

Amorphous ribbons show regular domains (rather than "flowing" patterns)

Amorphous ribbons show regular domains (rather than "flowing" patterns)

> Reason: Residual anisotropies

# Residual anisotropies in amorphous ribbons

 magnetization-induced minute deviations from random pair ordering





 stress-induced internal mechanical stress, e.g. due to differences in quenching speed

#### Stress-induced anisotropy


# As-quenched $Fe_{78}Si_{13}B_9$ amorphous ribbon



#### Amorphous ribbons: Magnetostriction & domains



same location, independently demagnetized  $\rightarrow$  local anisotropy



# As-quenched $Fe_{78}Si_{13}B_9$ amorphous ribbon



# Compare: stripe domains in magnetic films FeSiBCuNb amorphous film (2 µm thick)



H = 0



→ perpendicular anisotropy

Н

## Compare: stripe domains in magnetic films



low anisotropy
 (i.e.Q<<1) film
→ dense stripe domains</pre>

for comparison: high anisotropy film (garnet, Q>1)





# Compare: stripe domains in magnetic films



# Compare: stripe domains in magnetic films

#### amorphous thin film (2 µm thick)





#### amorphous ribbon (20 µm thick)





#### amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)







#### amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)







# amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)





10 **µ**m



#### amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)





CoFeSiB-alloy with  $\lambda_{c} \sim 0$ → no stress effects 





H = 0

Generation of anisotropy-free amorphous ribbons:

- magnetostriction-free ribbon (Co-based alloy)  $(T_{Curie} = 220^{\circ}C, T_{cryst} = 540^{\circ}C)$
- polished on both sides
- stress relieve annealed just below T<sub>crvst</sub> (at 430°C)
- cooled in rotating field

# Continuous magnetization-patterns

#### in magnetostriction-free metallic glass after annealing in rotating field





# Continuous magnetization-patterns

#### in magnetostriction-free metallic glass after annealing in rotating field



Continuously "flowing" patterns are possible in specially treated amorphous ribbons (suppression of residual anisotropies)

#### amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)



amorphous ribbon (20 µm thick) increasing perpendicular anisotropy (stress)



Continuously "flowing" patterns also occur in case of conflicting influences (anisotropy plays role)

(FeSiB)

# Summary: Coercivity and domains



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Nanocrystalline materials

# Nanocrystalline soft magnets

Nanocrystalline ribbon Fe<sub>73</sub>Si<sub>16</sub>B<sub>7</sub>Cu<sub>1</sub>Nb<sub>3</sub> (Finemet, Vitroperm)



amorphous ribbon 550°C nanocrystalline ribbon

rapid

quenching

Nanocrystalline materials

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## Coercivity and grain size









ferromagnetic correlation length (exchange length): minimum scale for appreciable variation of magnetization (parallel moments for L<Lex)



ferromagnetic correlation length (exchange length): minimum scale for appreciable variation of magnetization (parallel moments for L<Lex)



$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 





Fe<sub>80</sub>Si<sub>20</sub>:  

$$K_1 = 8 \text{ kJ/m}^3$$
  
 $A = 10^{-11} \text{ J/m}$   
 $- L_{ex} = \sqrt{A/K_1} = 35 \text{ nm}$   
 $- D < L_{ex}$ 





Fe<sub>80</sub>Si<sub>20</sub>:  

$$K_1 = 8 \text{ kJ/m}^3$$
  
 $A = 10^{-11} \text{ J/m}$   
 $- L_{ex} = \sqrt{A/K_1} = 35 \text{ nm}$   
 $- D < L_{ex}$ 





nm

 $\rightarrow$  D < L<sub>ex</sub>

random anisotropy model [Herzer 1989]: exchange interaction averages over anisotropy of individual grains



nm

 $\rightarrow$  D < L<sub>ex</sub>

random anisotropy model [Herzer 1989]: exchange interaction averages over anisotropy of individual grains

► 
$$\langle K_1 \rangle \approx |K_1| (D/L_{ex})^6 = 3 J/m^3$$
 -



very weak eff. anisotropy

 $\rightarrow$  D < L<sub>ex</sub>

random anisotropy model [Herzer 1989]: exchange interaction averages over anisotropy of individual grains

$$\blacktriangleright$$
  $\langle K_1 \rangle \approx |K_1| (D/L_{ex})^6 = 3 J/m^3 =$ 



very weak eff. anisotropy
# FeSiBCuNb: domain state

### amorphous (as-quenched)

# 100 **µ**m

### nanocrystalline

### nanocrystalline



homogeneous domains on macroscopic scale, direction determined by induced anisotropy

$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 

→  $L_{ex} = \sqrt{A/K_1} = 35 \text{ nm}$ exchange length

random anisotropy model

$$\rightarrow$$
  $\langle K_1 \rangle = 3 J/m^3$   
average anisotropy



$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 

→  $L_{ex} = \sqrt{A/K_1} = 35$  nm exchange length

random anisotropy model

$$- L_{ex} = \sqrt{A/\langle K_1 \rangle} = 2 \mu m$$
  
renormalized exchange length



### Nanocrystalline materials

# Comparison of domain walls



### Fe-Si Goss sheet, surface wall width: 150 nm



nanocrystalline ribbon, surface wall width: several µm

$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 

→  $L_{ex} = \sqrt{A/K_1} = 35$  nm exchange length

random anisotropy model

$$\checkmark$$
  $\langle K_1 \rangle = 2.3 J/m^3$   
average anisotropy

$$- L_{ex} = \sqrt{A/\langle K_1 \rangle} = 2 \mu m$$
  
renormalized exchange length



$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 

→  $L_{ex} = \sqrt{A/K_1} = 35$  nm exchange length

random anisotropy model

→ 
$$L_{ex} = \sqrt{A/\langle K_1 \rangle} = 2 \mu m$$
  
renormalized exchange length



 $L_{ex} = 2 \mu m$ 

$$Fe_{80}Si_{20}$$
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 $K_1 = 8 \text{ kJ/m}^3$   
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random anisotropy model

→ 
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renormalized exchange length



10 µm

$$Fe_{80}Si_{20}$$
:  
 $K_1 = 8 \text{ kJ/m}^3$   
 $A = 10^{-11} \text{ J/m}$ 

→  $L_{ex} = \sqrt{A/K_1} = 35$  nm exchange length

ra

# Manocrystalline Random anisotropy effect in Permalloy

coarse-grained material (grain size: 30 µm) fine-grained material (grain size: 13 µm)



# Permalloy: K<sub>cryst</sub> much smaller than in FeSi





# Manocrystalline Random anisotropy effect in Permalloy

coarse-grained material (grain size: 30 µm)



fine-grained material (grain size: 13 µm)



# Manocrystalline Interplay random/induced anisotropy





random anisotropy (K<sub>1</sub>):

modulated on scale of renormalized exchange length, ⟨K<sub>1</sub>⟩≈ 3 J/m<sup>3</sup>

• induced anisotropy Ku:

uniform on large scale, K<sub>u</sub> ≈ 3 - 30 J/m<sup>3</sup>

→ interplay

## Manocrystalline Interplay random/induced anisotropy



# Manocrystalline Interplay random/induced anisotropy



low induced anisotropy

strong creep-induced anisotropy

20 **µ**m

### Interplay random/induced anisotropy Nanocrystalline materials Nanocryst. core with longitudinal anisotropy $K_{u} = 29 \text{ J/m}^{3}$ $K_{\rm u} = 5 \, {\rm J}/{\rm m}^3$ $K_{\rm u} = 10 \text{ J/m}^3$ (weak) (strong) (moderate) 0.1 mm Η Ku 50 µm 50 **µ**m





$$\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$$
 N: number of grains within correlation volume

low induced anisotropy ( $K_u = 3 \text{ J/m}^3$ )

### strong induced anisotropy (K<sub>u</sub> = 30 J/m<sup>3</sup>)



### room temperature

$$\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$$
 N: number of grains within correlation volume

low induced anisotropy ( $K_u = 3 J/m^3$ )

### strong induced anisotropy $(K_u = 30 \text{ J/m}^3)$



$$\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$$

N: number of grains within correlation volume

low induced anisotropy  $(K_u = 3 J/m^3)$ 

### strong induced anisotropy $(K_u = 30 \text{ J/m}^3)$



350°C



$$\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$$
 N: nu

: number of grains within correlation volume

low induced anisotropy ( $K_u = 3 J/m^3$ )



strong induced anisotropy (K<sub>u</sub> = 30 J/m<sup>3</sup>)



550°C

350°C

### Nanocrystalline materials

 $\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$ 

# $Co_{45}Fe_{28.5}Si_{13.5}B_9Cu_1Nb_3$

### increases anisotropy of grains



sample: Pilar Marin, Madrid



# Patches and ripple

# Nanocrystalline Fe<sub>84</sub>Zr<sub>3.5</sub>Nb<sub>3.5</sub>B<sub>8</sub>Cu<sub>1</sub>

### 20 µm thick

### thinned to µm

### still thinner



patches





ripple

Excursion: Ripple phenomenon

### Cobalt (42 nm thick)



### $H = 0.15 H_k$















**λ**trans  $= \sin \vartheta_1 - \sin \vartheta_2$ 







# Ripple and patches

### ripple in films





### patches in thick materials



# Patches and ripple

### 20 µm thick thinned to µm still thinner

# 20 **µ**m

statistical perturbation by crystal anisotropy causes:

- patches in thick samples (ribbons)
- ripple in thin films

# Ripple phenomenon: Comparison Ni/Co

### Permalloy (10 nm thick)



### Co (6 nm thick)





# Ripple phenomenon: Comparison Ni/Co



### Nanocrystalline materials

 $\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$ 

# $Co_{45}Fe_{28.5}Si_{13.5}B_9Cu_1Nb_3$

### increases anisotropy of grains



sample: Pilar Marin, Madrid

# Summary: Coercivity and domains



# Summary: Coercivity and domains



### FeSiBCuNb: over-annealed

 $20^{\circ}C$ 

625°C

### 800°C



grain coarsening precepitation of borides
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Permanent magnets, basics

Nanocrystalline

permanent magnets





along texture axis

perpendicular texture axis

perpendicular texture axis

Thermally Thermally Magnetized demagnetized demagnetized What happens to domains, when grains get smaller, when structural length approaches nanometer regime (= single-domain regime)

along texture axis perpendicular texture axis perpendicular texture axis

Ensemble of single-domain grains (or particles)



#### Ensemble of single-domain grains (or particles)



# Expectation: each grain (particle) magnetized along its easy axis.

Ensemble of single-domain grains (or particles)



Ensemble of single-domain grains (or particles)



#### Ensemble of single-domain grains (or particles)



Details depend on grain interaction

















#### remanence > $0.5 M_s$









# Nanostructured NdFeB: exchange-spring magnet

#### remanent state



T. Schrefl and J. Fidler, IEEE Trans. Magn. 35, 3223 (1999)



# Nanostructured NdFeB: exchange-spring magnet

#### Bright field TEM image

# Foucault image

J. Chapman et al., 13th I nt. Workshop on RE Magnets and their Applications (1994)



# Nanostructured NdFeB: exchange-spring magnet

#### FeSiBCuNb overannealed





# 3 types of nanostructured NdFeB magnets

Isotropic magnets: Remanence ( $M_r = M_s/2$ )



exchanged coupled grains based on stoichiometric  $Nd_2Fe_{14}B$ 

Remanence enhancement for isotropic magnets



exchanged coupled grains based on nanocomposite Nd<sub>2</sub>Fe<sub>14</sub>B / <del>\alpha - Fe</del>

# 3 types of nanostructured NdFeB magnets

Isotropic magnets: Remanence ( $M_r = M_s/2$ )

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Remanence enhancement for isotropic \_ magnets



exchanged coupled grains based on nanocomposite Nd<sub>2</sub>Fe<sub>14</sub>B / <del>\alpha - Fe</del>



decoupled Nd<sub>2</sub>Fe<sub>14</sub>B grains separated by thin paramagnetic layer

Remanence enhancement by texturing

# Permanent magnets, basics

# isotropic anisotropic (textured) **1**] remanence = $0.5 M_s$ remanence > $0.5 M_s$ field



some 100 nm



some 100 nm



some 100 nm

observation perpendicular to texture axis





some 100 nm

coarse grains fine grains

Hot deformed NdFeB magnet (thermally demagnetized) (deformation degree ~ 76%, texture parameter  $(B_r || - B_r L)/B_r || = 0.79$ )

observed perpendicular to texture axis

#### grain structure





courtesy K. Khlopkov and O. Gutfleisch (IFW Dresden)

#### domains
































#### magnetization process along preferred axis











NdFeB grain size about 100 nm





after thermal demagnetization



after field demagnetization



10 **µ**m

MFM observation

courtesy K. Khlopkov and O. Gutfleisch (IFW Dresden)

#### Domains in Sm<sub>2</sub>Co<sub>17</sub> magnets

Sm(Co<sub>0.784</sub>Fe<sub>0.1</sub>Cu<sub>0.088</sub>Zr<sub>0.028</sub>)7.19 known as pinning magnet

c-axis perpendicular

c-axis parallel



#### Domains in Sm<sub>2</sub>Co<sub>17</sub> magnets

#### $Sm(Co_{0.784}Fe_{0.1}Cu_{0.088}Zr_{0.028})_{7.19}$

#### magnetic microstructure (Lorentz-TEM):



#### courtesy J. Fidler, Vienna

#### Domains in Sm<sub>2</sub>Co<sub>17</sub> magnets

quenched from 850°C
(low coercive state)

O. Gutfleisch et al., Acta Mater. 54 (2006)

slowly cooled to 400°C (optimally processed, high coercive state µ0Hc ≈ 3T)







## Domains in coarse-grained material

• wide volume domains fine surface domains

 domain width increases linearily with thickness (i.e. grain size)

 coercivity due to grain boundary effects







# Domains in nanocrystalline ribbons

- patchy modulation (connection to ripple), depends on induced anisotropy
- counterplay uniform induced anisotropy/ averaged magnetocrystalline anisotropy
- counterplay also explains:
  - patch domains for  $T > T_{c, amorph}$
  - irregularities in hard- and easy-axis magnetization process
- nucleation-dominated domain refinement (patch domains) at high f









# Domains in fine and nanostructured permanent magnets

 highly in for excl typical grain sizes: 20 - 300 nm  $Nd_2Fe_{14}B$ :  $K_u = 4.3 \cdot 10^6 \text{ kJ/m}^3$  $A = 8 \cdot 10^{-12} \text{ J/m}$ 

 magneto for decc

• 
$$L_{ex} = \sqrt{A/K_1} = 1.3 \text{ nm}$$

random anisotropy model irrelevant



# Domains in fine and nanostructured permanent magnets

 highly imobile patch domains for exchange coupled materials

 magnetostatic interaction domains for decoupled grains





Hirarchy of descriptive levels of magnetic materials

#### 5. Magnetic Hysteresis, or Magnetization Curve

Describing the *average magnetization* vector of a sample as a function of the external field (always applicable)

#### 4. Phase, or Magnetic Texture Analysis

Collecting domains of equal magnetization direction in "phases". More generally, describing the distribution function (*texture*) of magnetization directions (> 0.1 mm)

#### 3. Domain, or Magnetic Microstructure Analysis

Describing the *magnetic microstructure* of a sample, the shape and detailed spatial arrangement of domains and domain boundaries (1–1000 µm)

#### 2. Micromagnetic Analysis

Describing the *internal structure of domain walls* and their substructures in terms of a continuum theory of a classical magnetization vector field (1–1000 nm)

#### **1. Atomic Level Theory**

Describing the origin, the interactions, the mutual arrangement and the statistical thermodynamics of elementary magnetic moments (< 1 nm)

## Comparison of Domain Obervation Techniques



MFM: Magnetic Force Microscopy

SPT: Spin-Polarized Tunneling

MO: Magnetoptic Method

SEM: Scanning (reflection) Electron Microscopy TEM: Transmission Electron Microscopy

#### Resolution of optical microscopy (E. Abbe 1840 - 1905)



constructive interference diffraction limited image formation 0.5 **λ** ΝΑ Rayleigh equation: d = d = separation between particles, still allowing to see them  $\lambda$  = wavelength NA = numerical aperture of objective  $NA = n \sin \theta$  $\boldsymbol{\theta}$  = half the cone angle of Θ light accepted by objective n = referaction index of medium between sample and objective best around 200 nm

resolution determined by

## Comparison of Domain Obervation Techniques



MFM: Magnetic Force Microscopy

SPT: Spin-Polarized Tunneling

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## Comparison of Domain Obervation Techniques



MFM: Magnetic Force Microscopy

SPT: Spin-Polarized Tunneling

MO: Magnetoptic Method

SEM: Scanning (reflection) Electron Microscopy TEM: Transmission Electron Microscopy

# Kerr microscopy

#### Kerr effect

Kerr-effect: rotation of polarized light

polarizer

unpolarized

light



#### Wide-field Kerr microscope



# Hysteresis curve and magnetization process

#### Asymmetric reversal in exchange biased CoFe/IrMn



 $Co_{90}Fe_{10}$  (20 nm)  $Ir_{23}Mn_{77}$  (10 nm)

J. McCord, R.S., R. Mattheis, K.-U. Barholz, JAP 93, 5491 (2003)

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### Concertina decay and hysteresis



### Concertina decay and hysteresis



## Sample manipulation



M. Frommberger, J. McCord, E. Quandt: phys. stat. sol. (a) 201, 3319 (2004)

#### Kerr microscopy: high/low temperature observation



# Heating above T<sub>Curie</sub> of amorphous phase

$$\langle K_1 \rangle \sim \frac{K_1}{\sqrt{N}}$$
 N: number of exchange-coupled grains within correlation volume



#### room temperature

350°C

S. Flohrer, R.S., C. Polak, G. Herzer, Acta Mater. 53, 2937 (2005)

## Variable magnification

## Stress effects in trafo steel

initial state





transformer steel

# Change of magnification



## High-resolution observations

#### Co basal plane



amorphous layer (1  $\mu$ m thick)

#### asymmetric Bloch wall (met. Glass)



#### Crosstie wall (Permalloy)



## Quantitative Kerr microscopy

## Quantitative Kerr microscopy: principle





domains on (100)-FeSi sheet

## Quantitative Kerr microscopy: example

#### Domains in magnetostriction-free amorphous ribbon

as-quenched state

after annealing in rotating field







5 **µ**m

## Kerr microscopy: advantages

## Depth sensitivity

## Depth sensitivity of Kerr microscopy





# Dynamic and time-resolved Kerr microscopy

### Dynamic observations

FeSiB amorphous ribbon, as-quenched





#### Slow dynamics



#### 25 Hz sinusoidal field

# Time-resolved imaging: Stroboscopic mode

illumination intensity and repetition rate are limited

- → no single-shot imaging possible
- → accumulation of large number of independent events necessary (at fixed time delay)
- → requires repetitive magnetization processes !!



probing with defined time delay

periodic magnetic field excitation

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probing with defined time delay

periodic magnetic field excitation

## Low-frequency dynamics in amorphous ribbon



0.2 mm

slowly changing field (< Hz) H



decreasing field

remanence

## Stroboscopic wide-field microscopes



# Nanocrystalline core with weak Ku

S. Flohrer et al., Acta Mat. (2006)



Ku

## Summary: limitations of dynamics

Bulk metallic ferromagnets: eddy current effects dominate

Thick metallic films (1 µm): eddy currents dominate

Thin metallic films (<100 nm) or non-conducting materials eddy currents negligible spin precession

Heff

Μ

(for frequency in GHz regime)

## Landau-Lifshitz-Gilbert dynamics



H<sub>eff</sub> : acting magnetic field (embedding pulse field)

- α : damping parameter
- γ<sub>0</sub> : gyromagnetic ratio

static



dynamic

0 ns

0.28 ns

0.38 ns

0.64 ns

0.93 ns

15.76 ns





static



dynamic

0 ns

0.28 ns

0.38 ns

0.64 ns

0.93 ns

15.76 ns







static



dynamic

0 ns

0.28 ns

0.38 ns

0.64 ns

0.93 ns

15.76 ns



## Kerr microscopy: drawbacks

## Small objects?

#### Resolution of optical microscopy (E. Abbe 1840 - 1905)



constructive interference diffraction limited image formation 0.5 **λ** ΝΑ Rayleigh equation: d = d = separation between particles, still allowing to see them  $\lambda$  = wavelength NA = numerical aperture of objective  $NA = n \sin \theta$  $\boldsymbol{\theta}$  = half the cone angle of Θ light accepted by objective n = referaction index of medium between sample and objective best around 200 nm

resolution determined by

### About resolution Co elements (sample: Axel Carl)


# Magnetization reversal of Co-wires



courtesy J.McCord (IFW Dresden), sample: B. Hausmanns (Duisburg)

## Magnetization reversal of Co-wires



courtesy J.McCord (IFW Dresden), sample: B. Hausmanns (Duisburg)

# Sub-micrometer imaging

#### NiFe wires, 0.5 µm wide, 20 nm thick



together with: M. Kläui, T. Moore, U. Rüdiger (Konstanz), J. McCord (IFW Dresden),

after H<sub>ext</sub>

# Sub-micrometer imaging

#### NiFe wires, 0.5 µm wide, 20 nm thick



together with: M. Kläui, T. Moore, U. Rüdiger (Konstanz), J. McCord (IFW Dresden),

# Some Magneto-optics

### Kerr effect: dielectric law

$$\boldsymbol{D} = \boldsymbol{\varepsilon} \boldsymbol{E} = \boldsymbol{\varepsilon} \begin{pmatrix} 1 & -i Q m_3 & i Q m_2 \\ i Q m_3 & 1 & -i Q m_1 \\ -i Q m_2 & i Q m_1 & 1 \end{pmatrix} \boldsymbol{E}$$

 $= \varepsilon E + i \varepsilon Q m \times E$ 

- *E*: electric vector of light wave
- **D**: dielectric displacement vector
  - (= vector of light after reflection)
- *m*<sub>i</sub>: components of magnetization vector (cubic crystal)
- $\boldsymbol{\mathcal{E}}$ : dielectric tensor
- Q: material constant ( $\sim M_s$ , complex, determines strength of rotation)

### Kerr effect: dielectric law

$$D = \varepsilon E = \varepsilon \begin{pmatrix} 1 & -iQm_3 & iQm_2 \\ iQm_3 & 1 & -iQm_1 \\ -iQm_2 & iQm_1 & 1 \end{pmatrix} E$$
$$= \varepsilon E + i\varepsilon Qm \times E \longrightarrow \text{concept of Lorentz force}$$

**mx**E

m

- E: electric vector of light wave
- **D**: dielectric displacement vector
  - (= vector of light after reflection)
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### Kerr effect: Lorentz concept





# Depth selective Kerr microscopy





# Depth selective Kerr microscopy



# Magnetooptical microscopy: history



Michael Faraday (1791-1867)

small change of polarization plane due to magnetooptic interaction in transmission, circular birefringence, ~ M Fowler and Fryer, 1956

### About polarized light



superposition of two orthogonal transverse waves of <u>equal</u> phase

superposition of two orthogonal transverse waves of <u>different</u> phase

# About polarized light

Linearily polarized light = superposition of two circular waves of opposite rotation sense and equal frequency



# Circular birefringence

- if sample is illuminated parallel to the magnetization vector (k || m), the light wave can only propagate in two circularly polarized modes of opposite rotation sense
- due to the magnetization, both circular modes feel different refraction indices
  - → both modes propagate with different velocities
  - → modes are shifted in phase
  - → after leaving the sample they unify to plane-polarized wave again, which is rotated
  - circular magnetic birefringence (Faraday rotation)
- if also absorption:
  - → both modes are damped differently
  - → elliptical wave
  - circular magnetic dichroism (Faraday ellipticity)



# Faraday microscopy in transparent films



decreasing field

zero field

# Magnetooptical microscopy: history



Michael Faraday (1791-1867)

small change of polarization plane due to magnetooptic interaction in transmission, circular birefringence, ~ M

> John Kerr (1824-1907)

small change of polarization plane due to magnetooptic interaction in reflection, circular birefringence, ~ M

W. Voigt

(1850 - 1919)

Williams et al., 1951;

Fowler and Fryer,

1956

Fowler and Fryer, 1952

Dillon,

1958



small change of polarization state due to magnetooptic interaction in reflection, linear birefringence, ~ M<sup>2</sup>

Schäfer and Hubert, 1990



# Linear birefringence

- if sample is illuminated perpendicular to magnetization vector (k  $\perp$  m), the light wave can only propagate in two linearly polarized modes of orthogonal pol. direction
- one plane is along m, the other perpendicular to m
- due to the magnetization, both plane modes feel different refraction indices
  - → both modes propagate with different velocities
  - → modes are shifted in phase
  - → after leaving the sample they unify to elliptical wave
  - Inear magnetic birefringence (Voigt effect)
- requires compensator due to ellipticity



# Kerr-, Voigt- und Gradient Effects

#### Kerr Effect



polarizer

oblique incidence

#### Voigt and Gradient Effect





polarizer

perpendicular incidence, compensator

### Kerr-, Voigt- und Gradient Effects



#### Kerr Effect

crosstie wall in NiFe-film (50 nm thick)



#### Voigt- and Gradient-Effect

### Application of Gradient effect





#### FeSi (111) surface

#### Kerrcontrast

Gradient-Contrast

10 **µ**m